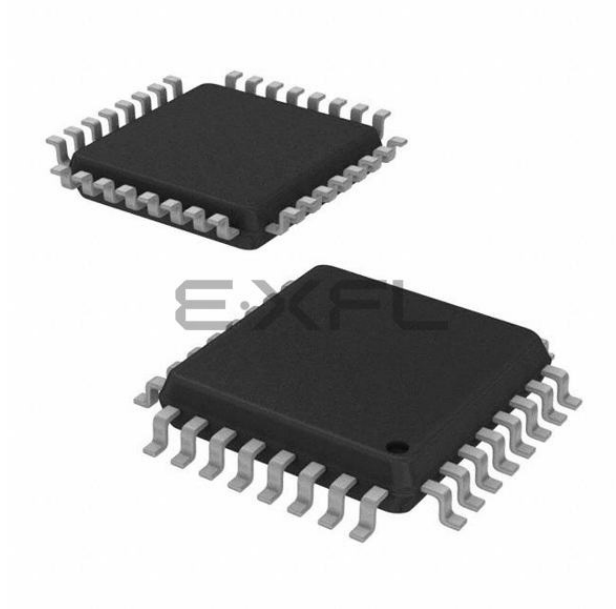

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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Not For New Designs
Core Processor	STM8A
Core Size	8-Bit
Speed	24MHz
Connectivity	I²C, LINbus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	25
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	2K x 8
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 7x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm8af6286tay

List of tables

3 Product line-up

Table 2. STM8AF526x/8x/Ax product line-up with CAN

Order code	Package	High density Flash program memory (bytes)	RAM (bytes)	Data EEPROM (bytes)	10-bit A/D chan.	Timers (IC/OC/PWM)	Serial interfaces	I/0 wakeup pins
STM8AF/P52AA	LQFP80 (14x14)	128 K	6 K	2 K	16	1x8-bit: TIM4 3x16-bit: TIM1, TIM2, TIM3 (9/9/9)	CAN, LIN(UART), SPI, USART, I²C	68/37
STM8AF/P528A		64 K						
STM8AF/P52A9	LQFP64 (10x10)	128 K						52/36
STM8AF/P5289		64 K						
STM8AF/P5269		32 K		1 K				
STM8AF/P52A8	LQFP48 (7x7)	128 K		2 K	10			38/35
STM8AF/P5288		64 K						
STM8AF/P5268		32 K		1K				
STM8AF/P5286	VFQFPN32 (5x5)	64 K		2 K	6	1x8-bit: TIM4 3x16-bit: TIM1, TIM2, TIM3 (8/8/8)	CAN, LIN(UART), I²C	25/24
STM8AF/P52A6		128 K						

Table 3. STM8AF6269/8x/Ax product line-up without CAN

Order code	Package	High density Flash program memory (bytes)	RAM (bytes)	Data EEPROM (bytes)	10-bit A/D chan.	Timers (IC/OC/PWM)	Serial interfaces	I/0 wakeup pins
STM8AF/P62AA	LQFP80 (14x14)	128 K	6 K	2 K	16	1x8-bit: TIM4 3x16-bit: TIM1, TIM2, TIM3 (9/9/9)	LIN(UART), SPI, USART, I²C	68/37
STM8AF/P628A		64 K						
STM8AF/P62A9	LQFP64 (10x10)	128 K						52/36
STM8AF/P6289		64 K		2 K				
STM8AF/P6269		32 K		1 K				
STM8AF/P62A8	LQFP48 (7x7)	128 K		2 K	10			38/35
STM8AF/P6288		64 K						
STM8AF/P6286	LQFP32 (7x7)				7	1x8-bit: TIM4 3x16-bit: TIM1, TIM2, TIM3 (8/8/8)	LIN(UART), SPI, I²C	25/23
STM8AF/P62A6	VFQFPN32 (5x5)	128 K						

5.2 Single wire interface module (SWIM) and debug module (DM)

5.2.1 SWIM

The single wire interface module, SWIM, together with an integrated debug module, permits non-intrusive, real-time in-circuit debugging and fast memory programming. The interface can be activated in all device operation modes and can be connected to a running device (hot plugging).The maximum data transmission speed is 145 bytes/ms.

5.2.2 Debug module

The non-intrusive debugging module features a performance close to a full-flavored emulator. Besides memory and peripheral operation, CPU operation can also be monitored in real-time by means of shadow registers.

- R/W of RAM and peripheral registers in real-time
- R/W for all resources when the application is stopped
- Breakpoints on all program-memory instructions (software breakpoints), except the interrupt vector table
- Two advanced breakpoints and 23 predefined breakpoint configurations

5.3 Interrupt controller

- Nested interrupts with three software priority levels
- 24 interrupt vectors with hardware priority
- Five vectors for external interrupts (up to 37 depending on the package)
- Trap and reset interrupts

5.4 Flash program and data EEPROM

- 32 Kbytes to 128 Kbytes of high density single voltage Flash program memory
- Up to 2 Kbytes true (not emulated) data EEPROM
- Read while write: writing in the data memory is possible while executing code in the Flash program memory.

The whole Flash program memory and data EEPROM are factory programmed with 0x00.

5.4.1 Architecture

- The memory is organized in blocks of 128 bytes each
- Read granularity: 1 word = 4 bytes
- Write/erase granularity: 1 word (4 bytes) or 1 block (128 bytes) in parallel
- Writing, erasing, word and block management is handled automatically by the memory interface.

5.9.3 Serial peripheral interface (SPI)

The devices covered by this datasheet contain one SPI. The SPI is available on all the supported packages.

- Maximum speed: 10 Mbit/s or $f_{MASTER}/2$ for master, 8 Mbit/s or f_{MASTER} /2 for slave
- Full duplex synchronous transfers
- Simplex synchronous transfers on two lines with a possible bidirectional data line
- Master or slave operation - selectable by hardware or software
- CRC calculation
- 1 byte Tx and Rx buffer
- Slave mode/master mode management by hardware or software for both master and slave
- Programmable clock polarity and phase
- Programmable data order with MSB-first or LSB-first shifting
- Dedicated transmission and reception flags with interrupt capability
- SPI bus busy status flag
- Hardware CRC feature for reliable communication:
  - CRC value can be transmitted as last byte in Tx mode
  - CRC error checking for last received byte

5.9.4 Inter integrated circuit (I^2C) interface

The devices covered by this datasheet contain one I^2C interface. The interface is available on all the supported packages.

- I^2C master features:
  - Clock generation
  - Start and stop generation
- I^2C slave features:
  - Programmable I^2C address detection
  - Stop bit detection
- Generation and detection of 7-bit/10-bit addressing and general call
- Supports different communication speeds:
  - Standard speed (up to 100 kHz),
  - Fast speed (up to 400 kHz)
- Status flags:
  - Transmitter/receiver mode flag
  - End-of-byte transmission flag
  - I^2C busy flag
- Error flags:
  - Arbitration lost condition for master mode
  - Acknowledgement failure after address/data transmission
  - Detection of misplaced start or stop condition
  - Overrun/underrun if clock stretching is disabled

Table 11. STM8AF526x/8x/Ax and STM8AF6269/8x/Ax pin description (continued)

Pin number					Pin name	Type	Input			Output				Main function (after reset)	Default alternate function	Alternate function after remap [option bit]
LQFP80	LQFP64	LQFP48	STM8AF62xx LQFP32/VFQFPN32	STM8AF52x6 VFQFPN32			Floating	Wpu	Ext. interrupt	High sink	Speed	OD	PP			
38	-	-	-	-	PH7/ TIM1_CH1N	I/O	**X**	X	-	-	O1	X	X	**Port H7**	Timer 1 - inverted channel 2	-
39	31	23	-	-	PE7/AIN8	I/O	**X**	X	-	-	O1	X	X	**Port E7**	Analog input 8	-
40	32	24			PE6/AIN9	I/O	**X**	X	X	-	O1	X	X	**Port E6**	Analog input 9	-
41	33	25	17	17	PE5/SPI_NSS(2)	I/O	**X**	X	X	-	O1	X	X	**Port E5**	SPI master/ slave select	-
42	-	-	-	-	PC0/ADC_ETR	I/O	**X**	X	X	-	O1	X	X	**Port C0**	ADC trigger input	-
43	34	26	18	18	PC1/TIM1_CH1	I/O	**X**	X	X	HS	O3	X	X	**Port C1**	Timer 1 - channel 1	-
44	35	27	19	19	PC2/TIM1_CH2	I/O	**X**	X	X	HS	O3	X	X	**Port C2**	Timer 1- channel 2	-
45	36	28	20	20	PC3/TIM1_CH3	I/O	**X**	X	X	HS	O3	X	X	**Port C3**	Timer 1 - channel 3	-
46	37	29	21	21	PC4/TIM1_CH4	I/O	**X**	X	X	HS	O3	X	X	**Port C4**	Timer 1 - channel 4	-
47	38	30	22	22	PC5/SPI_SCK(2)	I/O	**X**	X	X	-	O3	X	X	**Port C5**	SPI clock	-
48	39	31	-	-	V_{SSIO_2}	S	-	-	-	-	-	-	-	I/O ground		-
49	40	32	-	-	V_{DDIO_2}	S	-	-	-	-	-	-	-	I/O power supply		-
50	41	33	23	-	PC6/SPI_MOSI (2)	I/O	**X**	X	X	-	O3	X	X	**Port C6**	SPI master out/ slave in	-
51	42	34	24	-	PC7/SPI_MISO (2)	I/O	**X**	X	X	-	O3	X	X	**Port C7**	SPI master in/ slave out	-
52	43	35	-	23	PG0/CAN_TX	I/O	**X**	X	-	-	O1	X	X	**Port G0**	CAN transmit	-
53	44	36	-	24	PG1/CAN_RX	I/O	**X**	X	-	-	O1	X	X	**Port G1**	CAN receive	-
54	45	-	-	-	PG2	I/O	**X**	X	-	-	O1	X	X	**Port G2**	-	-

Table 13. I/O port hardware register map (continued)

Address	Block	Register label	Register name	Reset status
0x00 5014	Port E	PE_ODR	Port E data output latch register	0x00
0x00 5015		PE_IDR	Port E input pin value register	0xXX(1)
0x00 5016		PE_DDR	Port E data direction register	0x00
0x00 5017		PE_CR1	Port E control register 1	0x00
0x00 5018		PE_CR2	Port E control register 2	0x00
0x00 5019	Port F	PF_ODR	Port F data output latch register	0x00
0x00 501A		PF_IDR	Port F input pin value register	0xXX(1)
0x00 501B		PF_DDR	Port F data direction register	0x00
0x00 501C		PF_CR1	Port F control register 1	0x00
0x00 501D		PF_CR2	Port F control register 2	0x00
0x00 501E	Port G	PG_ODR	Port G data output latch register	0x00
0x00 501F		PG_IDR	Port G input pin value register	0xXX(1)
0x00 5020		PG_DDR	Port G data direction register	0x00
0x00 5021		PG_CR1	Port G control register 1	0x00
0x00 5022		PG_CR2	Port G control register 2	0x00
0x00 5023	Port H	PH_ODR	Port H data output latch register	0x00
0x00 5024		PH_IDR	Port H input pin value register	0xXX(1)
0x00 5025		PH_DDR	Port H data direction register	0x00
0x00 5026		PH_CR1	Port H control register 1	0x00
0x00 5027		PH_CR2	Port H control register 2	0x00
0x00 5028	Port I	PI_ODR	Port I data output latch register	0x00
0x00 5029		PI_IDR	Port I input pin value register	0xXX(1)
0x00 502A		PI_DDR	Port I data direction register	0x00
0x00 502B		PI_CR1	Port I control register 1	0x00
0x00 502C		PI_CR2	Port I control register 2	0x00

1. Depends on the external circuitry.

Table 18. Option bytes (continued)

Addr.	Option name	Option byte no.	Option bits								Factory default setting
			7	6	5	4	3	2	1	0	
0x00 480B	TMU	OPT6	TMU[3:0]								0x00
0x00 480C		NOPT6	NTMU[3:0]								0xFF
0x00 480D	Flash wait states	OPT7	Reserved							WAIT STATE	0x00
0x00 480E		NOPT7	Reserved							NWAIT STATE	0xFF
0x00 480F	Reserved										
0x00 4810	TMU	OPT8	TMU_KEY 1 [7:0]								0x00
0x00 4811		OPT9	TMU_KEY 2 [7:0]								0x00
0x00 4812		OPT10	TMU_KEY 3 [7:0]								0x00
0x00 4813		OPT11	TMU_KEY 4 [7:0]								0x00
0x00 4814		OPT12	TMU_KEY 5 [7:0]								0x00
0x00 4815		OPT13	TMU_KEY 6 [7:0]								0x00
0x00 4816		OPT14	TMU_KEY 7 [7:0]								0x00
0x00 4817		OPT15	TMU_KEY 8 [7:0]								0x00
0x00 4818		OPT16	TMU_MAXATT [7:0]								0xC7
0x00 4819 to 487D	Reserved										
0x00 487E	Boot-loader(1)	OPT17	BL [7:0]								0x00
0x00 487F		NOPT 17	NBL [7:0]								0xFF

1. This option consists of two bytes that must have a complementary value in order to be valid. If the option is invalid, it has no effect on EMC reset.

Table 19. Option byte description (continued)

Option byte no.	Description
OPT3	**LSI_EN: Low speed internal clock enable** 0: LSI clock is not available as CPU clock source 1: LSI clock is available as CPU clock source
	IWDG_HW: Independent watchdog 0: IWDG Independent watchdog activated by software 1: IWDG Independent watchdog activated by hardware
	WWDG_HW: Window watchdog activation 0: WWDG window watchdog activated by software 1: WWDG window watchdog activated by hardware
	WWDG_HALT: Window watchdog reset on Halt 0: No reset generated on Halt if WWDG active 1: Reset generated on Halt if WWDG active
OPT4	**EXTCLK: External clock selection** 0: External crystal connected to OSCIN/OSCOUT 1: External clock signal on OSCIN
	CKAWUSEL: Auto-wakeup unit/clock 0: LSI clock source selected for AWU 1: HSE clock with prescaler selected as clock source for AWU
	PRSC[1:0]: AWU clock prescaler 00: 24 MHz to 128 kHz prescaler 01: 16 MHz to 128 kHz prescaler 10: 8 MHz to 128 kHz prescaler 11: 4 MHz to 128 kHz prescaler
OPT5	**HSECNT[7:0]: HSE crystal oscillator stabilization time** This configures the stabilization time to 0.5, 8, 128, and 2048 HSE cycles with corresponding option byte values of 0xE1, 0xD2, 0xB4, and 0x00.
OPT6	**TMU**[3:0]: Enable temporary memory unprotection 0101: TMU disabled (permanent ROP). Any other value: TMU enabled.
OPT7	**WAIT STATE: Wait state configuration** This option configures the number of wait states inserted when reading from the Flash/data EEPROM memory. 0: No wait state 1: One wait state
OPT8	**TMU_KEY 1 [7:0]: Temporary unprotection key 0** Temporary unprotection key: Must be different from 0x00 or 0xFF
OPT9	**TMU_KEY 2 [7:0]: Temporary unprotection key 1** Temporary unprotection key: Must be different from 0x00 or 0xFF
OPT10	**TMU_KEY 3 [7:0]: Temporary unprotection key 2** Temporary unprotection key: Must be different from 0x00 or 0xFF
OPT11	**TMU_KEY 4 [7:0]: Temporary unprotection key 3** Temporary unprotection key: Must be different from 0x00 or 0xFF

10 Electrical characteristics

10.1 Parameter conditions

Unless otherwise specified, all voltages are referred to V_{SS}.

10.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at T_A = -40 °C, T_A = 25 °C, and $T_A = T_{Amax}$ (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production.

10.1.2 Typical values

Unless otherwise specified, typical data are based on T_A = 25 °C, V_{DD} = 5.0 V. They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range.

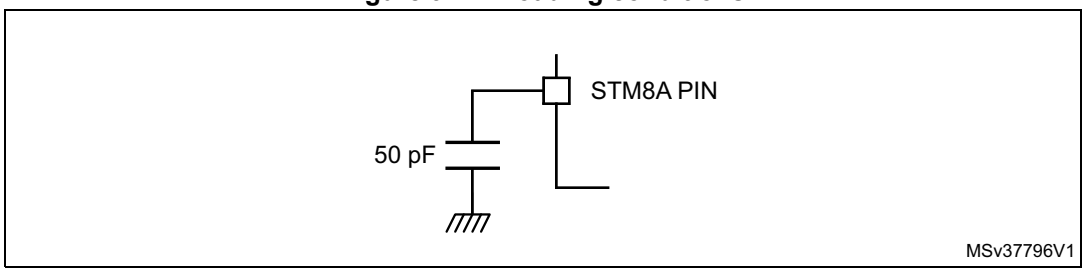
10.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

10.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 9*.

Figure 9. Pin loading conditions



10.3.6 I/O port pin characteristics

General characteristics

Subject to general operating conditions for V_{DD} and T_A unless otherwise specified. All unused pins must be kept at a fixed voltage, using the output mode of the I/O for example or an external pull-up or pull-down resistor.

Table 38. I/O static characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IL}	Low-level input voltage	-	-0.3 V		0.3 x V_{DD}	V
V_{IH}	High-level input voltage		0.7 x V_{DD}		V_{DD} + 0.3 V	
V_{hys}	Hysteresis(1)		-	0.1 x V_{DD}	-	
V_{OH}	High-level output voltage	Standard I/0, V_{DD} = 5 V, I = 3 mA	V_{DD} - 0.5 V	-	-	
		Standard I/0, V_{DD} = 3 V, I = 1.5 mA	V_{DD} - 0.4 V	-	-	
V_{OL}	Low-level output voltage	High sink and true open drain I/0, V_{DD} = 5 V I = 8 mA	-	-	0.5	V
		Standard I/0, V_{DD} = 5 V I = 3 mA	-	-	0.6	
		Standard I/0, V_{DD} = 3 V I = 1.5 mA	-	-	0.4	
R_{pu}	Pull-up resistor	V_{DD} = 5 V, V_{IN} = V_{SS}	35	50	65	kΩ
t_R, t_F	Rise and fall time (10% - 90%)	Fast I/Os Load = 50 pF	-	-	35(2)	ns
		Standard and high sink I/Os Load = 50 pF	-	-	125(2)	
		Fast I/Os Load = 20 pF	-	-	20(2)	
		Standard and high sink I/Os Load = 20 pF	-	-	50(2)	
I_{lkg}	Digital input pad leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	±1	µA
$I_{lkg\ ana}$	Analog input pad leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$ -40 °C < T_A < 125 °C	-	-	±250	nA
		$V_{SS} \leq V_{IN} \leq V_{DD}$ -40 °C < T_A < 150 °C	-	-	±500	
$I_{lkg(inj)}$	Leakage current in adjacent I/O(3)	Injection current ±4 mA	-	-	±1(3)	µA
I_{DDIO}	Total current on either V_{DDIO} or V_{SSIO}	Including injection currents	-	-	60	mA

1. Hysteresis voltage between Schmitt trigger switching levels. Guaranteed by characterization results, not tested in production.

2. Guaranteed by design.
3. Guaranteed by characterization results, not tested in production.

Figure 23. Typical V_{IL} and V_{IH} vs V_{DD} @ four temperatures

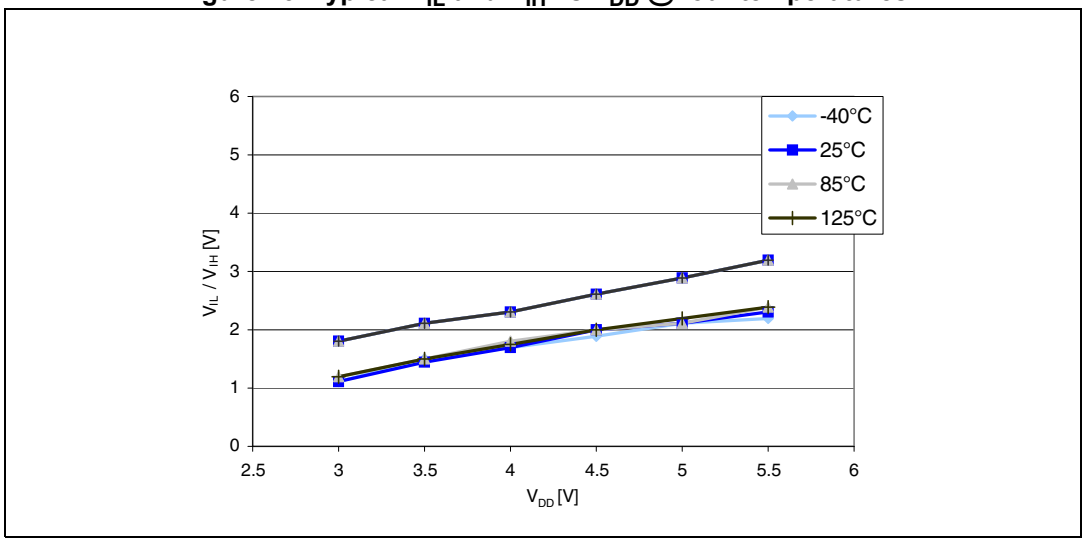
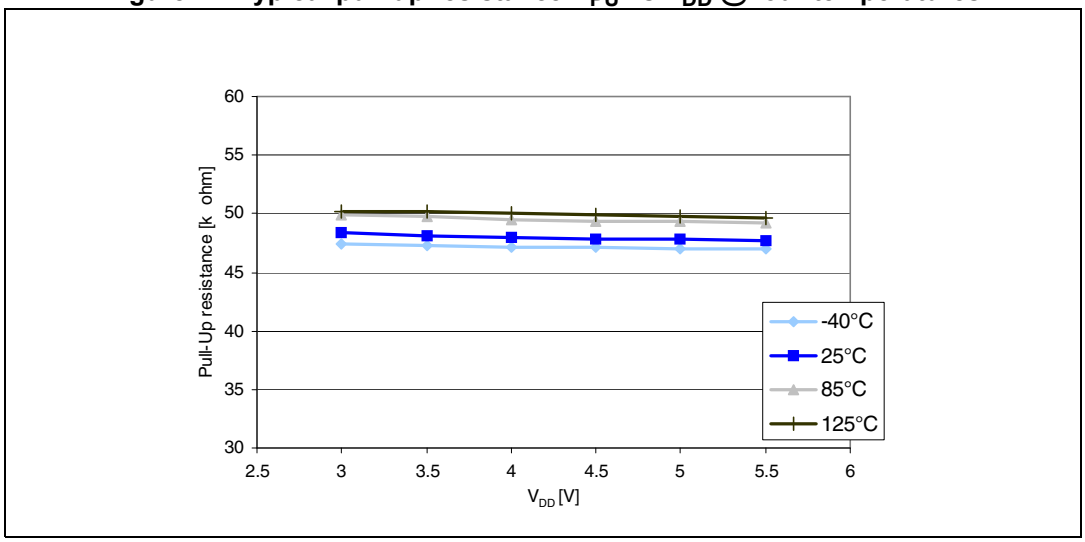


Figure 24. Typical pull-up resistance R_{PU} vs V_{DD} @ four temperatures



Static latch-up

Two complementary static tests are required on 10 parts to assess the latch-up performance.

- A supply overvoltage (applied to each power supply pin) and
- A current injection (applied to each input, output and configurable I/O pin) are performed on each sample.

This test conforms to the EIA/JESD 78 IC latch-up standard. For more details, refer to the application note AN1181.

Table 48. Electrical sensitivities

Symbol	Parameter	Conditions	Class(1)
LU	Static latch-up class	T_A = 25 °C	A
		T_A = 85 °C	
		T_A = 125 °C	
		T_A = 150 °C	

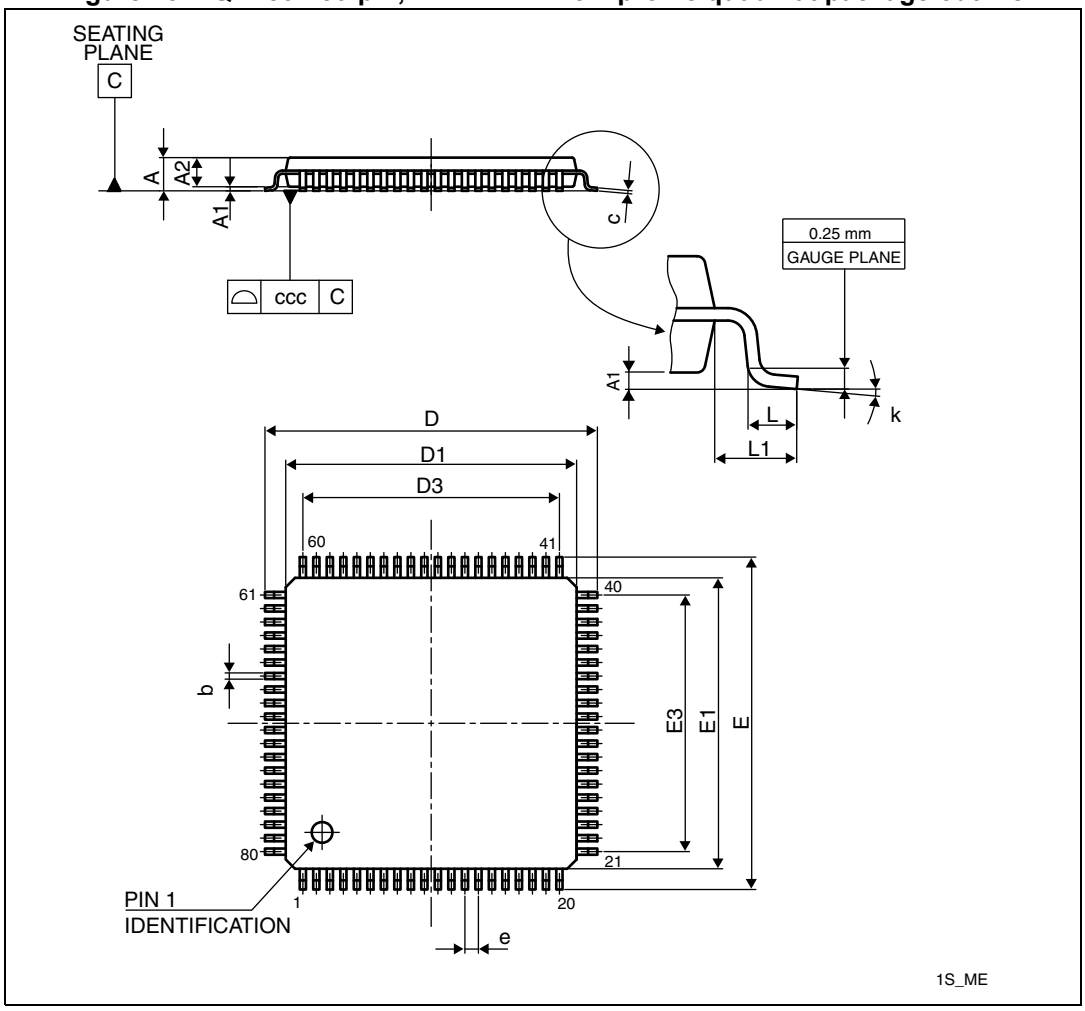
1. Class description: A Class is an STMicroelectronics internal specification. All its limits are higher than the JEDEC specifications, that means when a device belongs to class A it exceeds the JEDEC standard. B class strictly covers all the JEDEC criteria (international standard).

11 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK® is an ST trademark.

11.1 LQFP80 package information

Figure 45. LQFP80 - 80-pin, 14 x 14 mm low-profile quad flat package outline



1. Drawing is not to scale.

Table 49. LQFP80 - 80-pin, 14 x 14 mm low-profile quad flat package mechanical data(1)

Symbol	millimeters			inches		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.220	0.320	0.380	0.0087	0.0126	0.0150
c	0.090	-	0.200	0.0035	-	0.0079
D	15.800	16.000	16.200	0.6220	0.6299	0.6378
D1	13.800	14.000	14.200	0.5433	0.5512	0.5591
D3	-	12.350	-	-	0.4862	-
E	15.800	16.000	16.200	0.6220	0.6299	0.6378
E1	13.800	14.000	14.200	0.5433	0.5512	0.5591
E3	-	12.350	-	-	0.4862	-
e	-	0.650	-	-	0.0256	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.100	-	-	0.0039

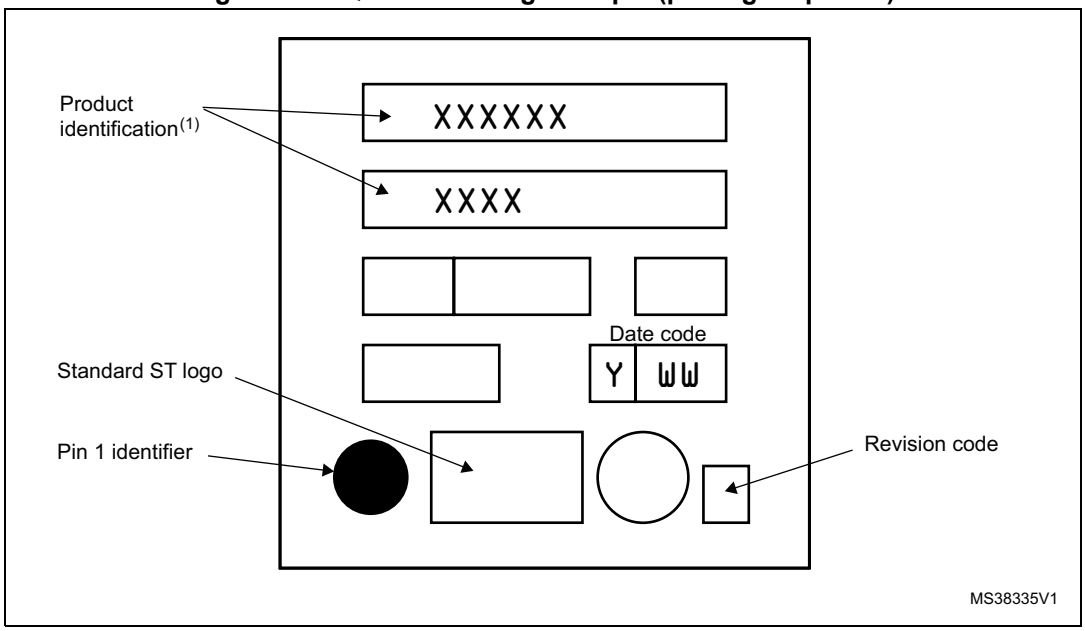
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Table 51. LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package mechanical data

Symbol	millimeters			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	8.800	9.000	9.200	0.3465	0.3543	0.3622
D1	6.800	7.000	7.200	0.2677	0.2756	0.2835
D3	-	5.500	-	-	0.2165	-
E	8.800	9.000	9.200	0.3465	0.3543	0.3622
E1	6.800	7.000	7.200	0.2677	0.2756	0.2835
E3	-	5.500	-	-	0.2165	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

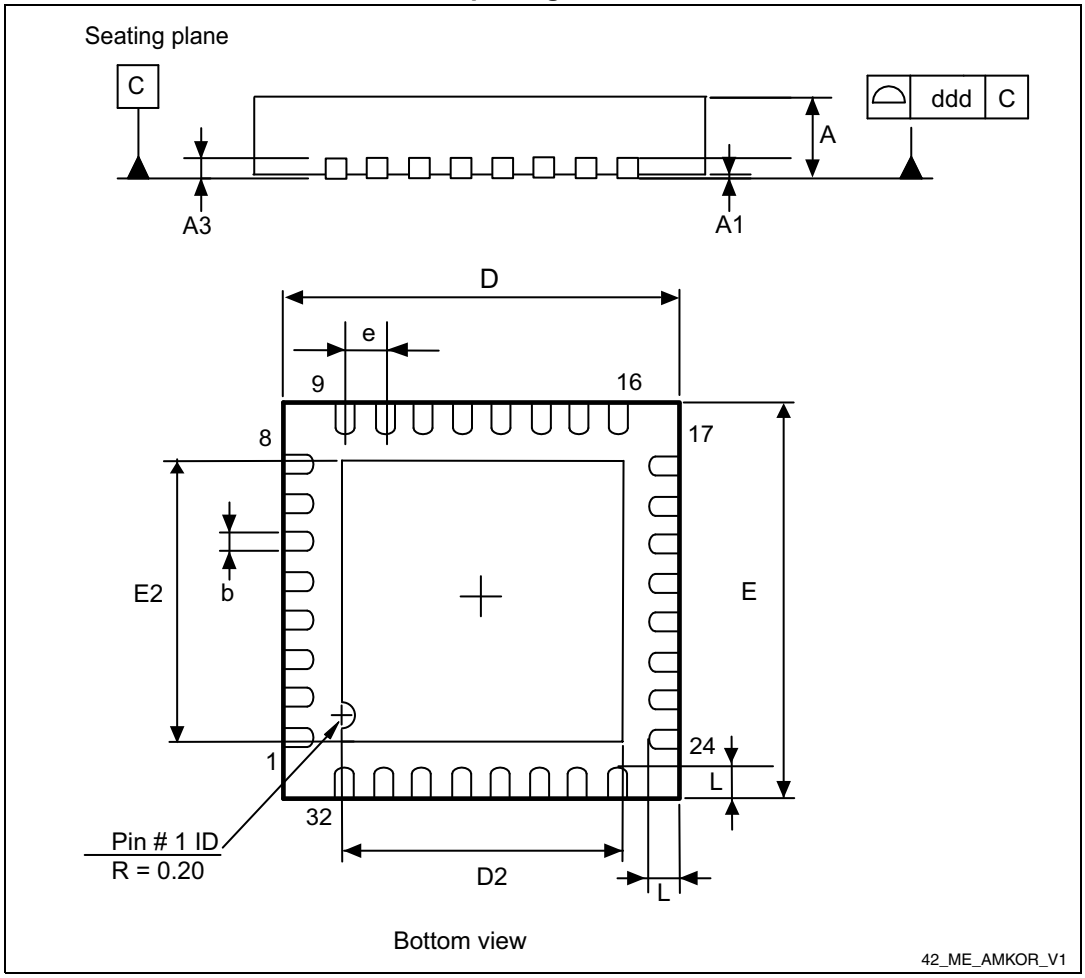
Figure 53. LQFP48 marking example (package top view)



1. Parts marked as "ES","E" or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST's quality department must be contacted to run a qualification activity prior to any decision to use these engineering samples.

11.5 VFQFPN32 package information

Figure 57. VFQFPN32 - 32-pin, 5x5 mm, 0.5 mm pitch very thin profile fine pitch quad flat package outline



1. Drawing is not to scale.

11.6 Thermal characteristics

In case the maximum chip junction temperature (T_{Jmax}) specified in *Table 24: General operating conditions* is exceeded, the functionality of the device cannot be guaranteed.

T_{Jmax}, in degrees Celsius, may be calculated using the following equation:

$$T_{Jmax} = T_{Amax} + (P_{Dmax} \times \Theta_{JA})$$

where:

T_{Amax} is the maximum ambient temperature in °C

Θ_{JA} is the package junction-to-ambient thermal resistance in ° C/W

P_{Dmax} is the sum of P_{INTmax} and $P_{I/Omax}$ ($P_{Dmax} = P_{INTmax} + P_{I/Omax}$)

P_{INTmax} is the product of I_{DD} and V_{DD}, expressed in Watts. This is the maximum chip internal power.

$P_{I/Omax}$ represents the maximum power dissipation on output pins

where:

$$P_{I/Omax} = \Sigma (V_{OL} * I_{OL}) + \Sigma((V_{DD} - V_{OH}) * I_{OH})$$

taking into account the actual V_{OL} / I_{OL} and V_{OH} / I_{OH} of the I/Os at low- and high-level in the application.

Table 54. Thermal characteristics(1)

Symbol	Parameter	Value	Unit
Θ_{JA}	Thermal resistance junction-ambient LQFP 80 - 14 x 14 mm	38	°C/W
	Thermal resistance junction-ambient LQFP 64 - 10 x 10 mm	46	
	Thermal resistance junction-ambient LQFP 48 - 7 x 7 mm	57	
	Thermal resistance junction-ambient LQFP 32 - 7 x 7 mm	59	
	Thermal resistance junction-ambient VFQFPN 32 - 5 x 5 mm	25	

1. Thermal resistances are based on JEDEC JESD51-2 with 4-layer PCB in a natural convection environment.

11.6.1 Reference document

JESD51-2 integrated circuits thermal test method environment conditions - natural convection (still air). Available from www.jedec.org.

14 Revision history

Table 55. Document revision history

Date	Revision	Changes
31-Jan-2008	1	Initial release
22-Aug-2008	2	Added 'H' products to the datasheet (Flash no EEPROM). *Section : Features* on cover page: Updated Memories, Reset and supply management, Communication interfaces and I/Os; reduced wakeup pins by 1. *Table 1: Device summary*: Removed STM8AF6168, STM8AF6148, STM8AF6166, STM8AF6146, STM8AF5168, STM8AF5186, STM8AF5176, and STM8AF5166. *Section 1: Introduction*, *Section 5: Product overview*, *Section 9: Option bytes*, *Section 6.2: Alternate function remapping*, *Table 21: Current characteristics:* Updated reference documentation: RM0009, PM0047, and UM0470. *Section 2: Description*: added information about peak performance. *Section 3: Product line-up*: Removed *STM8A common features* table. *Table 4: Peripheral clock gating bits (CLK_PCKENR1):* Removed STM8AF5186T, STM8AF5176T, STM8AF5168T, and STM8AF5166T. *Table 5: Peripheral clock gating bits (CLK_PCKENR2)*: Removed STM8AF6168T, STM8AF6166T, STM8AF6148T, and STM8AF6146T. *Section 5: Product overview*: Made minor content changes and improved readability and layout. *Section 5.5.3: 128 kHz low-speed internal RC oscillator (LSI)*: Major modification, TMU included. *Section 5.5.2: 16 MHz high-speed internal RC oscillator (HSI)*: User trimming updated. *Section 5.5.3: 128 kHz low-speed internal RC oscillator (LSI)*: LSI as CPU clock added. *Section 5.5.4: 24 MHz high-speed external crystal oscillator (HSE)*, *Section 5.5.5: External clock input*: Maximum frequency conditional 32 Kbyte/128 Kbyte. *Section 5.8: Analog to digital converter (ADC)*: Scan for 128 Kbyte removed. *Section 5.9: Communication interfaces*, *Section 5.9.3: Serial peripheral interface (SPI)*: SPI 10 Mb/s. *Figure 3: LQFP 80-pin pinout*, *Figure 4: LQFP 64-pin pinout*, *Figure 6: STM8AF62xx LQFP/VFQFPN 32-pin pinout*: Amended footnote 1. *Table 12: Memory model 128K:* HS output changed from 20 mA to 8 mA. *Section 7: Memory and register map*: Corrected *Table 8: Register and memory map*; removed address list; added *Table 14: General hardware register map*. *Section 10.3.2: Supply current characteristics* Note on typical/WC values added.